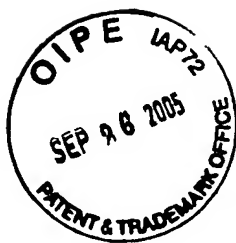


JCO6 Rec'd PCT/PTO 26 SEP 2005

PCT



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

APPLICATION OF: Axel Gerlt et al.  
SERIAL NO: 10/541,815 GROUP ART UNIT: Not assigned  
FILED: July 8, 2005 EXAMINER: Not assigned  
CUSTOMER NO.: 27162  
FOR: ORGANO-RESISTIVE MEMORY UNIT  
ATTY/DKT NO.: 411000-136

Mail Stop Amendment  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

SIR:

Pursuant to 37 C.F.R. §1.56(a), Applicant(s) hereby cite(s) the enclosed documents listed on the attached copy of Form PTO-1449 which are believed to be material to the patentability of the above-identified application.

This Information Disclosure Statement is filed in accordance with the paragraph of 37 CFR §1.97 indicated below:

X §1.97(b) This Information Disclosure Statement is filed:

- (1) Within three months of the filing date of a national application; OR
- (2) Within three months of the date of entry of the national stage of an international application; OR
- (3) Before the mailing of a first Office Action on the merits. No fee or statement is required.

\_\_\_\_ §1.97(c) This Information Disclosure Statement is filed after the period specified in paragraph (b) above, but before the mailing date of either:

- (1) A Final Action or under 37 CFR §1.113; OR
- (2) A Notice of Allowance under 37 CFR §1.311; AND

is accompanied by either: (check one)

- \_\_\_\_\_ The statement as specified in 37 CFR §1.97(e) set out below; OR  
\_\_\_\_\_ The fee of \$180.00 under 37 CFR §1.17(p).

\_\_\_\_§1.97(d) This Information Disclosure Statement is filed after the mailing date of either:

- (1) a Final Action or under 37 CFR §1.113; OR
  - (2) A Notice of Allowance under 37 CFR §1.311;
- BUT filed on or before payment of the Issue Fee; AND  
is accompanied by:
- (1) The statement as specified in 37 CFR §1.97(e) as set forth below; AND
  - (2) Petition is hereby made under 37 CFR §1.97(d) for consideration of this Information Disclosure Statement; AND,
  - (3) The petition fee of \$180.00 set out in 37 CFR §1.17(i).

\_\_\_\_§1.97(e) The undersigned Attorney hereby states that:

- \_\_\_\_\_ each item of information contained in this Information Disclosure Statement was first cited in any communication from a foreign patent office in a counterpart foreign application not more than three months prior to the filing date of this Information Disclosure Statement;  
or  
\_\_\_\_\_ no item of information contained in this Information Disclosure Statement was cited in a communication from a foreign patent office in a counterpart foreign application, or to the knowledge of the undersigned Attorney after making reasonable inquiry, was known to any individual designated in 37 CFR §1.56(c) more than three months prior to the filing date of the Information Disclosure Statement.

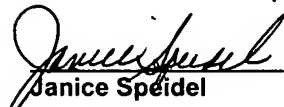
The relevancy of the cited patents, the foreign language and other documents listed on the attached PTO 1449 is that these documents were cited in the copending applications noted in the accompanying Disclosure Statement or were cited in a foreign application that may have subject matter generally related to the subject matter of one or more of the cited copending applications.

The Commissioner is authorized to charge payment of any fees associated with this communication or credit any overpayment to Deposit Account No. 03-0678.

**FIRST CLASS CERTIFICATE**

I hereby certify that this correspondence is being deposited on the date set forth below with the U.S. Postal Service as First Class Mail, postage prepaid, in an envelope addressed to:

Mail Stop Amendment  
Commissioner for Patents  
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Alexandria VA 22313-1450

  
Janice Speidel  
#270029

Sept. 23, 2005  
Date

Respectfully submitted,  
Axel Gerlt et al.

  
William Squire  
Reg. No. 25,378  
CARELLA, BYRNE, BAIN, GILFILLAN,  
CECCHI, STEWART & OLSTEIN  
5 Becker Farm Road  
Roseland, NJ 07068  
Tel: (973)994-1700  
Fax: (973)994-1744



Substitute for form 1449A/PTO

# **INFORMATION DISCLOSURE STATEMENT BY APPLICANT**

(Use as many sheets as necessary)

## **Complete if Known**

Application Number	10/541,815
Filing Date	July 8, 2005
First Named Inventor	Axel Gerlt
Group Art Unit	Not assigned
Examiner Name	Not assigned
Attorney Docket Number	411000-136

Sheet	1	Of	11
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## **U.S. PATENT DOCUMENTS**

Examiner Initial*	Cite No. <sup>1</sup>	Document Number Number-Kid Code <sup>2</sup> (if known)	Publication- Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		US-2002/0022284	02-21-2002	Heeger	See accompanying IDS Letter and Disclosure Statement filed herewith
		US-2002/0053320	05-09-2002	Duthaler	
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		US-5,206,525	04-27-1993	Yamamoto et al.	

# **INFORMATION DISCLOSURE STATEMENT BY APPLICANT**

*(Use as many sheets as necessary)*

## ***Complete if Known***

<p>Application Number</p> <p>Filing Date</p> <p>First Named Inventor</p> <p>Group Art Unit</p> <p>Examiner Name</p>	10/541,815
	July 8, 2005
	Axel Gertt
	Not assigned
	Not assigned
	411000-136

Sheet	2	11
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		US-5,259,926	11-09-1993	Kuwabara et al.	
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# **INFORMATION DISCLOSURE STATEMENT BY APPLICANT**

*(Use as many sheets as necessary)*

***Complete if Known***

				Application Number	10/541,815
				Filing Date	July 8, 2005
				First Named Inventor	Axel Gertt
				Group Art Unit	Not assigned
				Examiner Name	Not assigned
Sheet	3		11	Attorney Docket Number	411000-136

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Examiner Initial*	Cite No. <sup>1</sup>	Foreign Patent Document Country Code <sup>3</sup> Number <sup>4</sup> Kind Code <sup>5</sup> (if known)	Publication- Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T <sup>6</sup>
		DE 33 38 597	05-02-1985	GAO Gesellschaft		
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# **INFORMATION DISCLOSURE STATEMENT BY APPLICANT**

(Use as many sheets as necessary)

*Complete if Known*

Sheet	4		11	Application Number	10/541,815
				Filing Date	July 8, 2005
				First Named Inventor	Axel Gertt
				Group Art Unit	Not assigned
				Examiner Name	Not assigned
				Attorney Docket Number	411000-136

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Substitute for form 1449A/PTO

# **INFORMATION DISCLOSURE STATEMENT BY APPLICANT**

(Use as many sheets as necessary)

*Complete if Known*

<b>INFORMATION DISCLOSURE STATEMENT BY APPLICANT</b>  <i>(Use as many sheets as necessary)</i>	Application Number		10/541,815	
	Filing Date		July 8, 2005	
	First Named Inventor		Axel Gerlt	
	Group Art Unit		Not assigned	
	Examiner Name		Not assigned	
Sheet	5	11	Attorney Docket Number	411000-136

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		GR2001P03239 (not available)				
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Substitute for form 1449A/PTO  <b>INFORMATION DISCLOSURE STATEMENT BY APPLICANT</b>  <i>(Use as many sheets as necessary)</i>				<b>Complete if Known</b>	
				Application Number	10/541,815
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				First Named Inventor	Axel Gerlt
				Group Art Unit	Not assigned
				Examiner Name	Not assigned
Sheet	6		11	Attorney Docket Number	411000-136

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		WO 02/19443	03-07-2002	Siemens		
		WO 02/29912	04-11-2002	Cambridge University		X
		WO 02/43071	05-30-2002	Thin Film Electronics		X
		WO 02/47183	06-13-2002	Siemens		
		WO 03/046922	06-05-2003	Infineon Technologies		
		WO 03/067680	08-14-2003	Canon Kabushiki Kaisha		X
		WO 03/069552	08-21-2003	Rafsec Oy		X
		WO 03/081671	10-02-2003	Siemens AK		
		WO 03/095175	11-20-2003	ZBD Displays Ltd.		
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		WO 97/12349	04-03-1997	DeRivaz		X
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Substitute for form 1449A/PTO  <b>INFORMATION DISCLOSURE STATEMENT BY APPLICANT</b>  <i>(Use as many sheets as necessary)</i>				<b>Complete if Known</b>	
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				Group Art Unit	Not assigned
				Examiner Name	Not assigned
Sheet	7		11	Attorney Docket Number	411000-136

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		WO 99/10939	03-04-1999	Koninklijke Philips		X
		WO 99/21233	04-29-1999	Regents of U California		X
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Under the Paperwork Reduction Act of 1995, no persons are required to respond to a collection of information unless it displays a valid OMB control number

Substitute for form 1449A/PTO  <div style="text-align: center;"><b>INFORMATION DISCLOSURE STATEMENT BY APPLICANT</b></div> <div style="text-align: center; margin-top: 10px;"><i>(Use as many sheets as necessary)</i></div>				<div style="text-align: center;"><b><i>Complete if Known</i></b></div> <table border="1" style="width: 100%; border-collapse: collapse;"> <tr> <td style="width: 50%;">Application Number</td> <td>10/541,815</td> </tr> <tr> <td>Filing Date</td> <td>July 8, 2005</td> </tr> <tr> <td>First Named Inventor</td> <td>Axel Gertl</td> </tr> <tr> <td>Group Art Unit</td> <td>Not assigned</td> </tr> <tr> <td>Examiner Name</td> <td>Not assigned</td> </tr> <tr> <td>Attorney Docket Number</td> <td>411000-136</td> </tr> </table>		Application Number	10/541,815	Filing Date	July 8, 2005	First Named Inventor	Axel Gertl	Group Art Unit	Not assigned	Examiner Name	Not assigned	Attorney Docket Number	411000-136
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First Named Inventor	Axel Gertl																
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Examiner Name	Not assigned																
Attorney Docket Number	411000-136																
Sheet	8	Of	11														

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				First Named Inventor	Axel Gerlt
				Group Art Unit	Not assigned
				Examiner Name	Not assigned
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Examiner Signature			Date Considered

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APPLICATION      Axel Gerlt et al.  
OF:  
SERIAL NO:        10/541,815                      GROUP ART UNIT:    Not assigned  
FILED:             July 8, 2005                      EXAMINER:           Not assigned  
:                                      CUSTOMER NO.       27162  
FOR:                Organo-Resistive Memory Unit  
ATTY/DKT NO.:    411000-136

Mail Stop Amendment  
Commissioner for Patents  
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**DISCLOSURE STATEMENT UNDER 37 CFR 1.56**

SIR:

This paper is to bring to the attention of the PTO the following commonly owned copending U.S. applications, all of which are related in different respects to organic electronic devices and/or method of making such devices such as transistors, diodes, integrated circuits and the like. Many of these applications also have one or more common inventors. The enclosed PTO 1449 lists these applications. It is respectfully requested that the Examiner consider and make of record all of the cited applications listed on the attached PTO 1449.

<u>Application No.</u>	<u>Title</u>	<u>Inventors</u>	<u>Atty. Dkt. No.</u>
10/332,140	Method for the Production and Configuration of Organic Field-Effect Transistors (OFET)	Adolf Berndts et al.	411000-103

10/344,951	Organic Field-Effect Transistor (OFET), A Production Method Therefor, An Integrated Circuit Constructed From the Same and Their Uses	Adolf Bernds et al.	411000-99
10/362,932	Organic Field Effect Transistor, Method for Structuring an OFET and Integrated Circuit	Adolf Bernds et al	411000-110
10/380,113	Organic Rectifier, Circuit, RFID Tag and Use of an Organic Rectifier	Adolf Bernds et al.	411000-106
10/380,206	Organic Memory, Identification Marker (RFID-TAG) with Organic Memory and Uses of an Organic Memory	Adolf Bernds et al.	411000-102
10/381,032	Electrode and/or Conductor Track for Organic Components and Production Method Thereof	Adolf Bernds et al.	411000-105
10/433,959	Organic Field Effect Transistor, Method For Structuring an OFET and Integrated Circuit	Adolf Bernds	411000-108
10/433,961	Device For Detecting and/or Transmitting at Least One Environmental Influence, Method for Producing Said Device and Use Thereof	Wolfgang Clemens et al.	411000-111
10/467,636	Organic Field Effect Transistor With a Photostructured Gate Dielectric, Method for the Production and Use Thereof in Organic Electronics	Adolf Bernds et al.	411000-104
10/473,050	Device With At Least Two Organic Electronic Components and Method for Producing the Same	Adolf Bernds et al.	411000-113
10/479,234	Organic Field Effect Transistor, Method for Production and Use Thereof in the Assembly of Integrated Circuits	Adolf Bernds et al.	411000-101
10/479,238	Method For Producing Conductive Structures by Means of Printing Technique, and Active Components Produced Therefrom For Integrated Circuits	Adolf Bernds et al.	411000-100
10/492,922	Insulator for An Organic Electronic Component	Erwann Guillet et al.	411000-115
10/492,923	Electronic Unit, Circuit Design for the Same and Production Method	Wolfgang Clemens et al.	411000-114
10/498,610	Organic Field Effect Transistor with Offset Threshold Voltage and the Use Thereof	Walter Fix et al.	411000-119
10/508,640	Logic Component Comprising Organic Field Effect Transistors	Walter Fix et al.	411000-120



10/508,737	Device and Method for Laser Structuring Functional Polymers and	Adolf Bernds et al.	411000-121
10/517,750	Substrate for an Organic Field Effect Transistor, Use of the Substrate, Method of Increasing the Charge Carrier Mobility and Organic Field Effect Transistor (OFET)	Wolfgang Clemens et al.	411000-122
10/523,216	Electronic Component Comprising Predominantly Organic Functional Materials And A Process For The Production Thereof	Adolf Bernds et al.	411000-123
10/523,487	Electronic Device	Wolfgang Clemens et al.	411000-124
10/524,646	Organic Component for Overvoltage Protection and Associated Circuit	Walter Fix et al.	411000-127
10/533,756	Organic Electronic Component with High-Resolution Structuring and Process for the Production Thereof	Wolfgang Clemens et al.	411000-128
10/534,678	Measuring Apparatus for Determining an Analyte in a Liquid Sample	Wolfgang Clemens et al.	411000-129
10/535,448	Organic Electronic Component Comprising Semi-Conductive Functional Layer and Method for Producing Said Component	Wolfgang Clemens et al.	411000-131
10/535,449	Organic Electronic Component Comprising the Same Organic Material for at Least Two Functional Layers	Adolf Bernds et al.	411000-132
10/344,926	An Electronic Circuit Having an Encapsulated Organic-Electronic Component, and a Method for Making an Encapsulated Organic-Electronic Component	Wolfgang Clemens et al.	411000-133
10/541,815	Organo-Resistive Memory Unit	Axel Gerlt et al.	411000-136
10/541,956	Board or Substrate for an Organic Electronic Device and Use Thereof	Wolfgang Clemens et al.	411000-137
10/541,957	Organic Field Effect Transistor And Integrated Circuit	Walter Fix et al.	411000-138
10/543,561	Organic Storage Component and Corresponding Triggering Circuit	Wolfgang Clemens et al.	411000-139
10/542,678	Organic Electronic Component and Method For Producing Organic Electronic Devices	Adolf Bernds et al.	411000-140
10/542,679	Use of Conductive Carbon Black/Graphite Mixtures for the Production of Low-Cost Electronics	Adolf Bernds et al.	411000-141

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Janice Speidel Sept. 23, 2005  
Date

Respectfully submitted,  
Axel Gerlt et al.

  
William Squire  
Reg. No. 25,378  
CARELLA, BYRNE, BAIN, GILFILLAN,  
CECCHI, STEWART & OLSTEIN  
5 Becker Farm Road  
Roseland, NJ 07068  
Tel: (973)994-1700  
Fax: (973)994-1744

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U.S. PATENT DOCUMENTS					
Examiner Initial*	Cite No. <sup>1</sup>	Document Number ----- Number-Kid Code <sup>2</sup> (if known)	Publication- Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
	103	US-6,852,583	10/09/2003	Adolf Bernds et al.	See accompanying Disclosure Statement filed herewith
	102	US-6,903,958	03/21/2002	Adolf Bernds et al.	
	133	US-10/344,926	02/12/2004	Adolf Bernds et al.	
	99	US-10/344,951	02/12/2004	Adolf Bernds et al.	
	110	US-10/362,932	10/02/2003	Adolf Bernds et al.	
	106	US-10/380,113	09/25/2003	Adolf Bernds et al.	
	105	US-10/381,032	02/12/2004	Adolf Bernds et al.	
	108	US-10/433,959	04/01/2004	Adolf Bernds	
	111	US-10/433,961	04/01/2004	Wolfgang Clemens et al.	
	109	US-10/451,108	05/13/2004	Mark Giles et al.	
	104	US-10/467,636	11/04/2004	Adolf Bernds et al.	
	113	US-10/473,050	05/20/2004	Adolf Bernds et al.	
	101	US-10/479,234	12/30/2004	Adolf Bernds et al.	
	100	US-10/479,238	10/20/2004	Adolf Bernds et al.	
	115	US-10/492,922	03/03/2005	Erwann Bullet et al.	
	114	US-10/492,923	12/23/2004	Wolfgang Clemens et al.	
	119	US-10/498,610	N/A	Walter Fix et al.	
	120	US-10/508,640	N/A	Walter Fix et al.	
	121	US-10/508,737	N/A	Adolf Bernds et al.	
	122	US-10/517,750	N/A	Wolfgang Clemens et al.	
	123	US-10/523,216	N/A	Adolf Bernds et al.	
	124	US-10/523,487	N/A	Wolfgang Clemens et al.	
	127	US-10/524,646	N/A	Walter Fix et al.	
	128	US-10/533,756	N/A	Wolfgang Clemens et al.	

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	129	US-10/534,678	N/A	Wolfgang Clemens et al.	
	131	10/535,448	N/A	W. Clemens et al.	
	132	10/535,449	N/A	Walter Fix et al.	
	136	US-10/541,815	N/A	Axel Gerlt et al.	
	137	US-10/541,956	N/A	Wolfgang Clemens et al.	
	138	US10/541,957	N/A	Walter Fix et al.	
	139	US-10/543,561	N/A	Wolfgang Clemens et al.	
	140	US-10/542,678	N/A	Adolf Bemds et al.	
	141	US-10/542,679	N/A	Adolf Bemds et al.	
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